

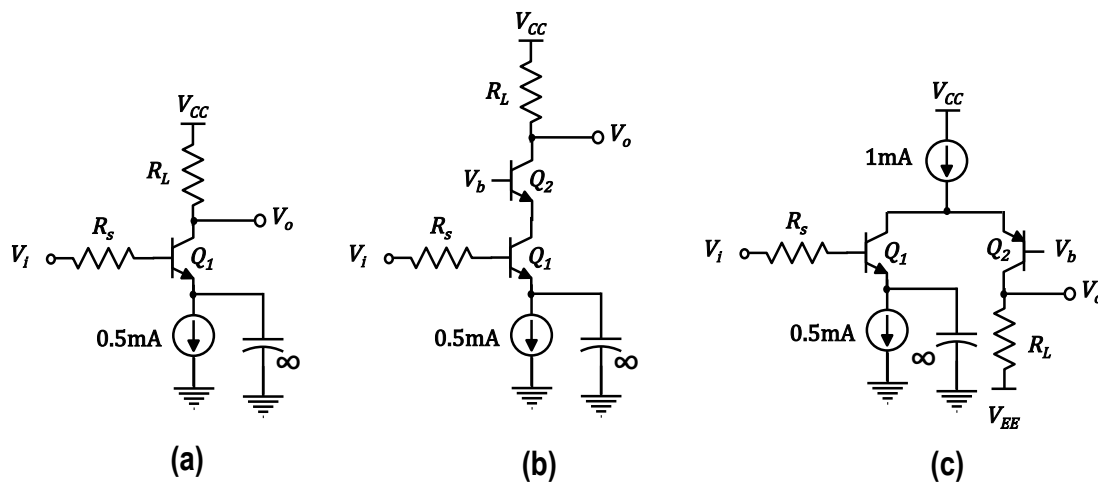
**PROBLEM SET #3**

*Issued: Tuesday, Sep. 15, 2015*

*Due (at 8 a.m.): Wednesday, Sep. 23, 2015, in the EE 140/240A HW box near 125 Cory.*

\*Unless otherwise stated, assume all the transistors are properly biased in the saturation region.

1. For each of the amplifiers in Fig. PS3-1,  $V_{CC}=20V$ ,  $R_S = R_L = 10k\Omega$ ,  $V_b = 5V$ , and  $V_{EE} = -10V$ . For all BJTs:  $\beta = 100$ ,  $C_\mu = 2pF$ , and  $f_T = 400MHz$ . Ignore Early effect and  $C_{CS}$ .
  - (a) Find the mid-band gain  $A = V_o/V_i$ , the 3-dB frequency  $\omega_H$ , and the gain-bandwidth product  $GBW = |A\omega_H|$ .
  - (b) Briefly compare the results obtained from part (a) for the three amplifiers and identify advantages or disadvantages between the three amplifiers. Hint: Consider the following metrics: power consumption, output voltage swing, gain, bandwidth, and GBW.



**Fig. PS3-1**

2. For the amplifier shown in Fig. PS3-2,  $V_{DD} = 5V$ ,  $R_S = 1k\Omega$ ,  $R_1 = 5k\Omega$ ,  $R_D = 4k\Omega$ ,  $R_B = 0.8k\Omega$ ,  $R_L = 50\Omega$ , and  $C_1 = C_2 = \infty$ . All transistors have the same parameters  $V_{th0} = 0.75V$ ,  $C_{ox} = 15fF/\mu m^2$ ,  $\mu_n C_{ox} = 50\mu A/V^2$ ,  $\lambda = 0$ , and  $C_{ov} = 0.75fF/\mu m$ . You can ignore  $C_{db}$  and  $C_{sb}$ . All channel lengths are  $0.5\mu m$ .
  - (a) Calculate  $R_2$ ,  $W_1$ , and  $W_2$  such that the overdrive voltage of both  $M_1$  and  $M_2$  are  $250mV$  and the voltage at the point  $A$  is equal to  $2V$  when no input signal is applied.
  - (b) Find midband voltage gain  $V_o/V_i$ ,  $R_{in}$ , and  $R_{out}$ .
  - (c) Find the  $\omega_H$  of the circuit. Point out which capacitor dominates.

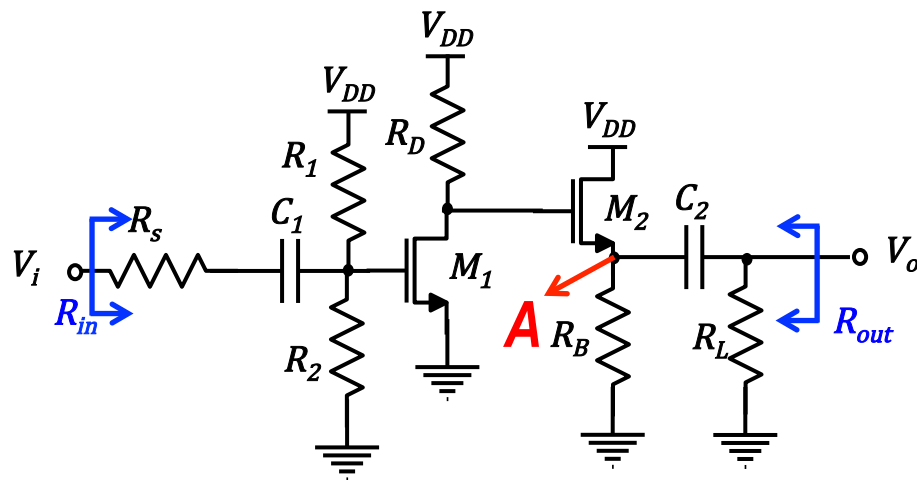


Fig. PS3-2

3. Consider the common-source amplifier with source resistance  $R_S$  in fig. PS3-3.
- Derive an expression for the mid-band gain  $V_o/V_i$ .
  - Find the  $\omega_H$  of the circuit. You can neglect  $C_{sb}$  and  $C_{db}$ .
  - Given that  $R_{in} = 100\text{k}\Omega$ ,  $g_m = 4\text{mA/V}$ ,  $R_L = 5\text{k}\Omega$ ,  $C_{gs} = C_{gd} = 1\text{pF}$ , calculate the low-frequency gain  $A$ , 3-dB frequency  $\omega_H$ , and gain-bandwidth product  $\text{GBW} = |A\omega_H|$  for  $R_S = 0, 100\Omega, 250\Omega$ , respectively.
  - Based on the result in (c), what's the effect of  $R_S$  on gain and bandwidth?

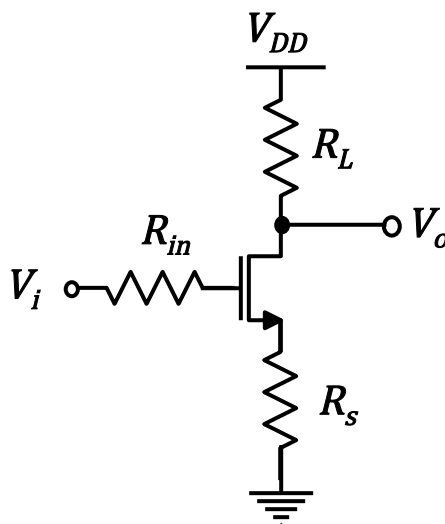


Fig. PS3-3

4. Suppose the BJTs in the amplifier of Fig. PS3-4 have the same  $\beta = 100$ ,  $V_A = 100\text{V}$ ,  $C_\mu = 0.2\text{pF}$ , and  $C_{je} = 0.8\text{pF}$ . At a bias current of  $100\mu\text{A}$ , the 2 BJTs have the same  $f_T = 400\text{MHz}$ . You can neglect  $C_{cs}$ .
- Find the mid-band gain  $V_o/V_i$  and the input resistance  $R_{in}$ .
  - Find the  $\omega_H$  of the circuit. Point out which capacitor dominates.
  - Find the mid-band gain  $V_o/V_i$  and  $\omega_H$  of the circuit with the bias current increased to  $1\text{mA}$ .
  - Briefly compare the results of parts (a), (b), and (c). What is the benefit you got from increasing the bias current?

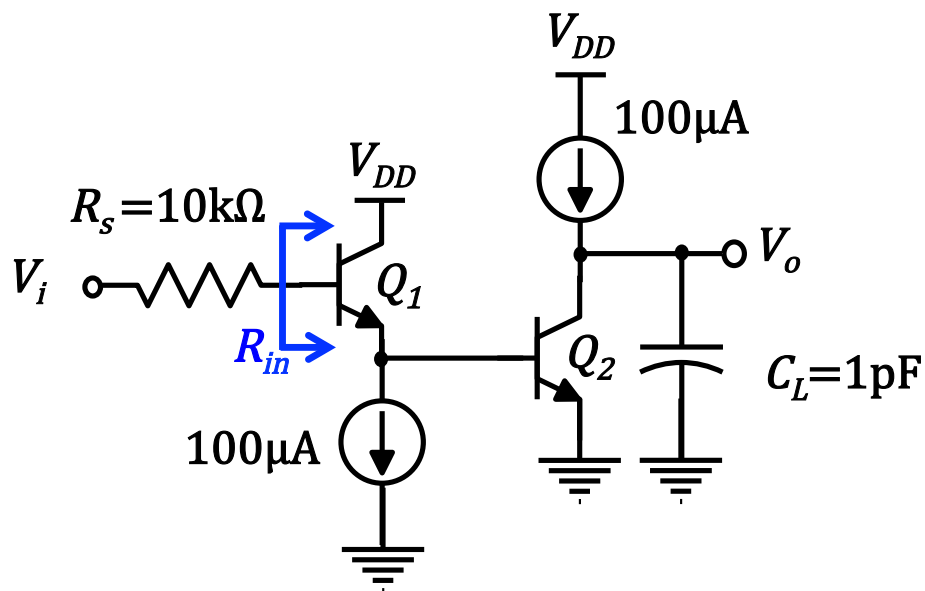


Fig. PS3-4